An R&D path for the muColl silicon tracker



- Request for the muColl tracker
- State of the art of LGAD-based 4D sensors
- Path forward for a muColl tracker based on UFSD_RSD

N. Bartosik, <u>N. Cartiglia</u>, N. Pastrone INFN, Torino

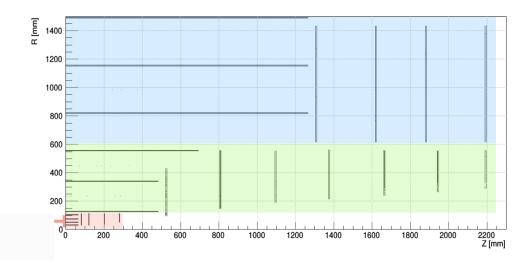
Setting the stage: resolution and occupancy

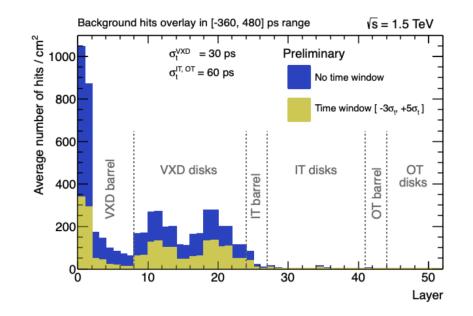
Silicon sensors with high spatial and timing resolution

- Outer Tracker $\sigma_{\phi} \sim 7 \ \mu m$, $\sigma_z \sim 90 \ \mu m \ \sigma_t \sim 60 \ ps$ (strips)
- Inner Tracker $\sigma_{\emptyset} \sim 7 \ \mu m$, $\sigma_z \sim 90 \ \mu m \ \sigma_t \sim 60 \ ps$ (macropixels)
- Vertex Detector $\sigma_{\emptyset} \sim 5 \ \mu m$, $\sigma_z \sim 5 \ \mu m \ \sigma_t \sim 30 \ ps \ (pixel, 25x25 \ \mu m)$
 - double layers with 2mm spacing
 - forward disks placed outside of the regions with highest BIB flux to minimize occupancy

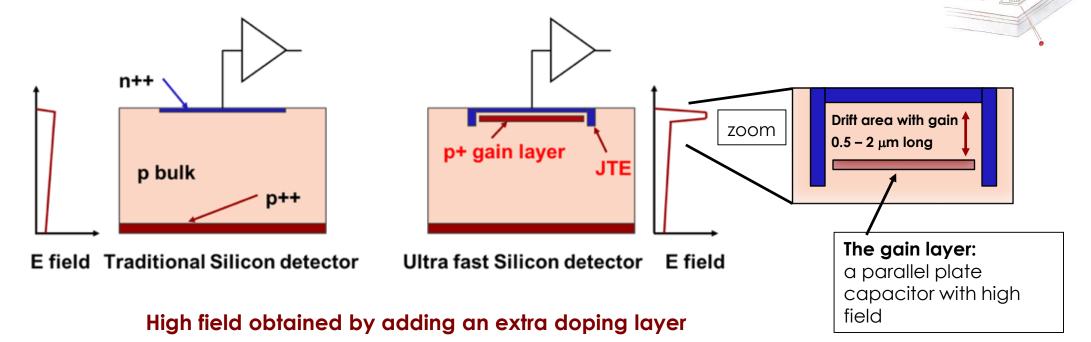
Fairly stringent requests for resolutions Very high occupancy in the vertex detector To be combined with:

- As low as possible material budget
- As low as possible power consumption





First design innovation: low gain avalanche diode (LGAD



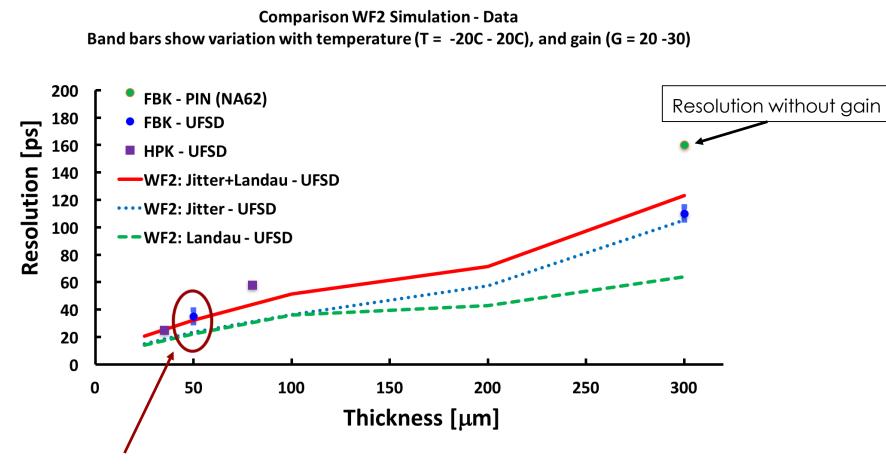
E ~ 300 kV/cm, closed to breakdown voltage

- The low-gain mechanism, obtained with a moderately doped p-implant, is the defining feature of the design.
- The low gain allows segmenting and keeping the shot noise below the electronic noise, since the leakage current is low.

Low gain is the key ingredient to good temporal resolution

LGAD optimized for timing are often called Ultra-Fast Silicon Detector (UFSD)

Summary of UFSD temporal resolution



There are now hundreds of measurements on 45-55 $\mu\text{m}\text{-thick}$ UFSDs

→ Current sensor choice for the ATLAS and CMS timing layers

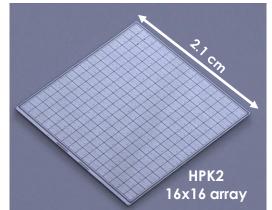
UFSD: State-of-the art

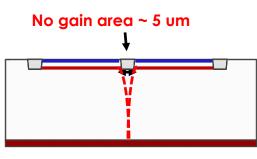
No gain area ~ 50 um



JTE + p-stop design

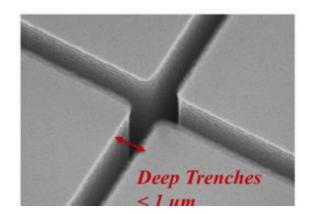
- CMS && ATLAS choice
- Not 100% fill factor
- Hit contained in a single pixel
- Very well tested
- High Occupancy OK
- Rate ~ 50-100 MHz
- Rad hardness ~ 2-3E15 n/cm2





Trench-isolated design

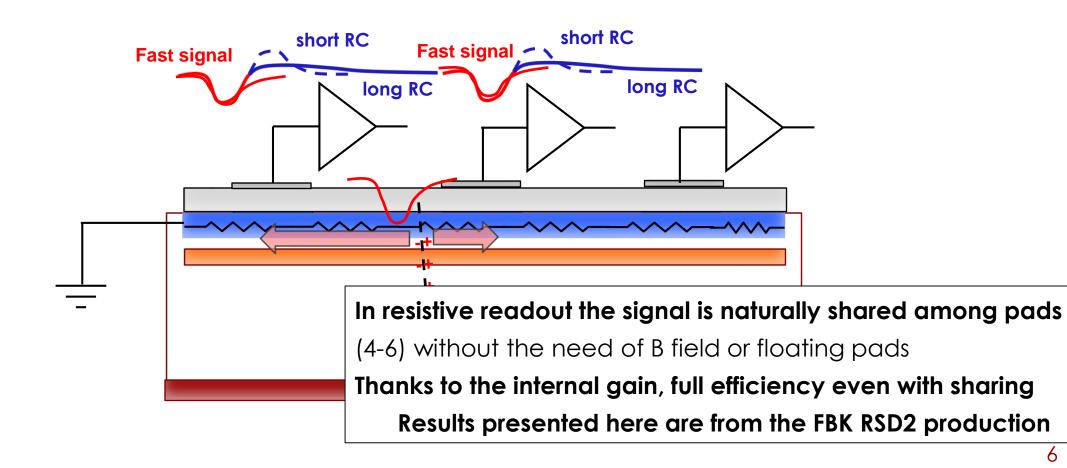
- Almost 100% fill factor
- Hit contained in a single pixel
- Temporal resolution (50 μ m) : 35-40 ps
- High Occupancy OK
- Rate ~ 50-100 MHz
- Rad hardness: ~ 1E15 n/cm2





Second design innovation: resistive read-out

- The signal is formed on the n+ electrode ==> no signal on the AC pads •
- The AC pads offer the smallest impedance to ground for the fast signal .
- The signal discharges to ground .



12/10 MUCol

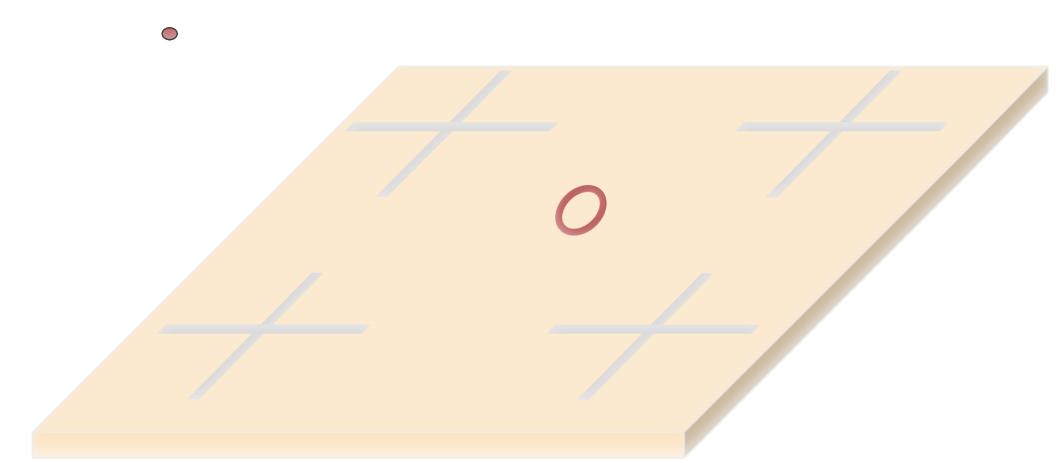
, INFN Torino

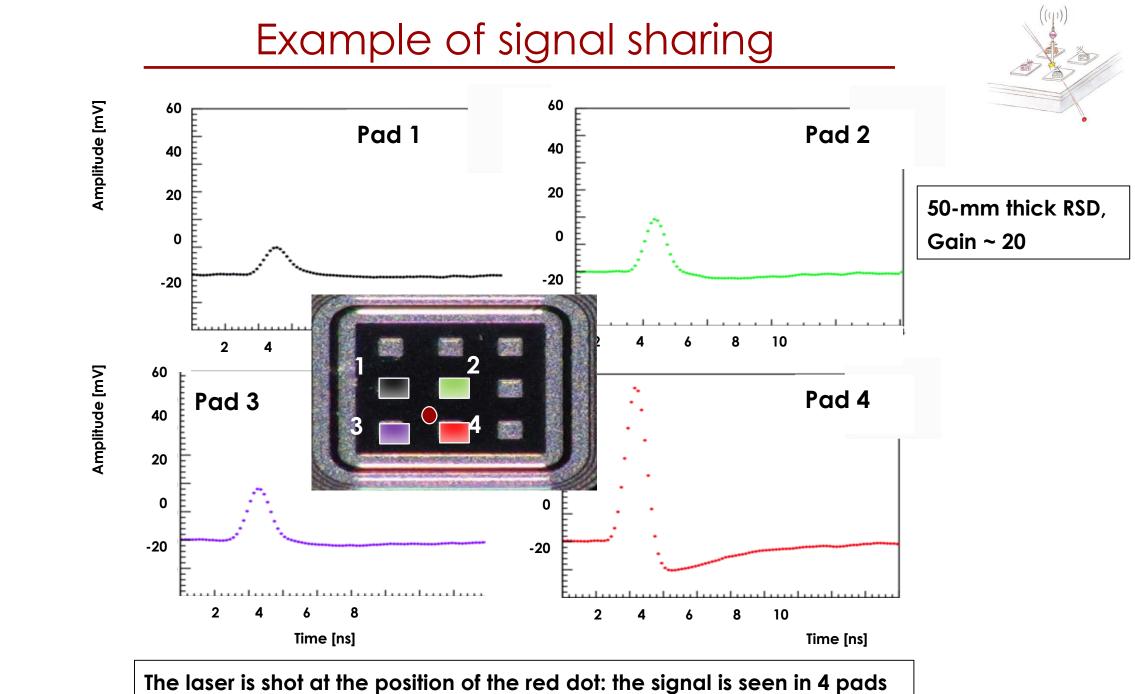
Cartiglia

Z

RSD principle of operation in motion







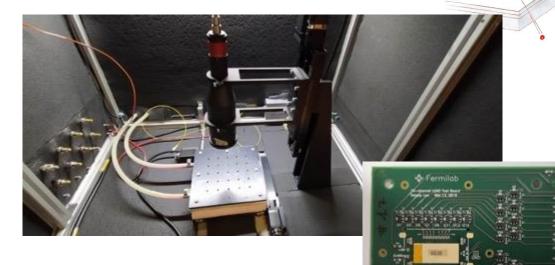
Experimental set-up

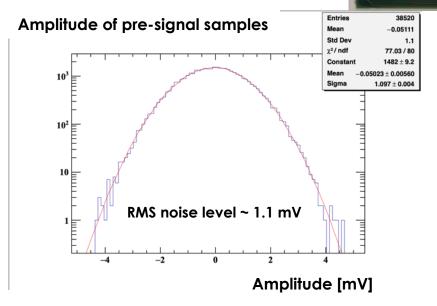
The Particulars TCT laser setup has been used:

- IR laser generates a signal in the RSD,
- simulating the passage of a MIP
- laser spot size ~ 8 µm
- Laser temporal precision: ~ 8 ps
- movable x-y stage provides reference positions of the laser shots, precision: $\sigma_{\text{Laser}} \sim 2 \, \mu m$

Sensors are read out with 16-ch fast analogue board, developed at FNAL

The signals are recorded with 16-ch CAEN Digitizer (5 Gs)



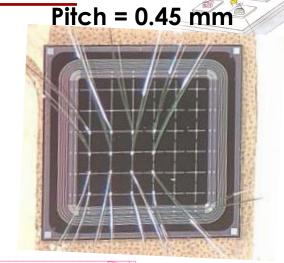


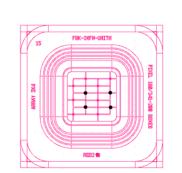
9

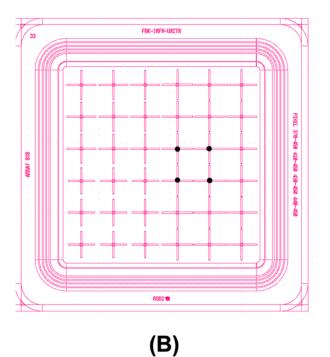
RSD2 structures used in this analysis (FBK - RSD2 production)

In this study, the perfomance of sensors with electrodes shaped as crosses is presented.

4 different dimensions: 200, 340, 450, and 1300 μm



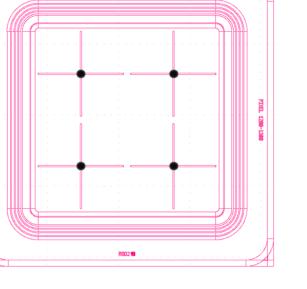




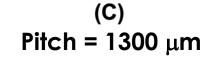
Pitch = 450 μ m

(A) 200 x 340 μm²

(A) x 340



FBK-THFH-UNITH



RSD position resolution (FBK RSD2 production)



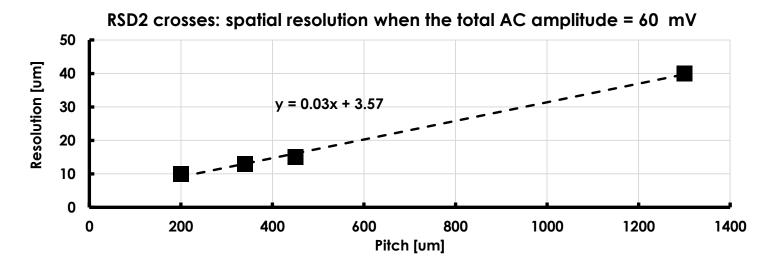
RSDs at gain = 30 achieve a spatial resolution of about 2-3% of the pitch size:

- 1300 x 1300 mm²: σ_x ~ 30 μm
- **450 x 450 mm²:** σ_x ~ 5 μm

Compared to a standard pixel

- 1300 x 1300 mm²: σ_x ~ 920 μm
- 450 x 450 mm²: σ_x ~ 320 μm

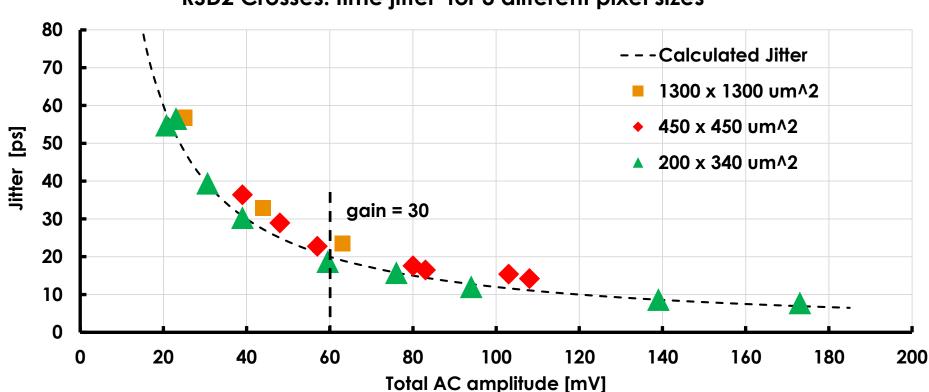
100 90 – – – 1300 um gain = 3080 🔶 - 450 um [m] 70 - 340 um 60 – 🖿 – 200 um 50 40 30 20 10 20 120 140 40 80 100 160 0 60 Total AC amplitude [mV]



RSD2 crosses: spatial resolution for 4 different pitch sizes

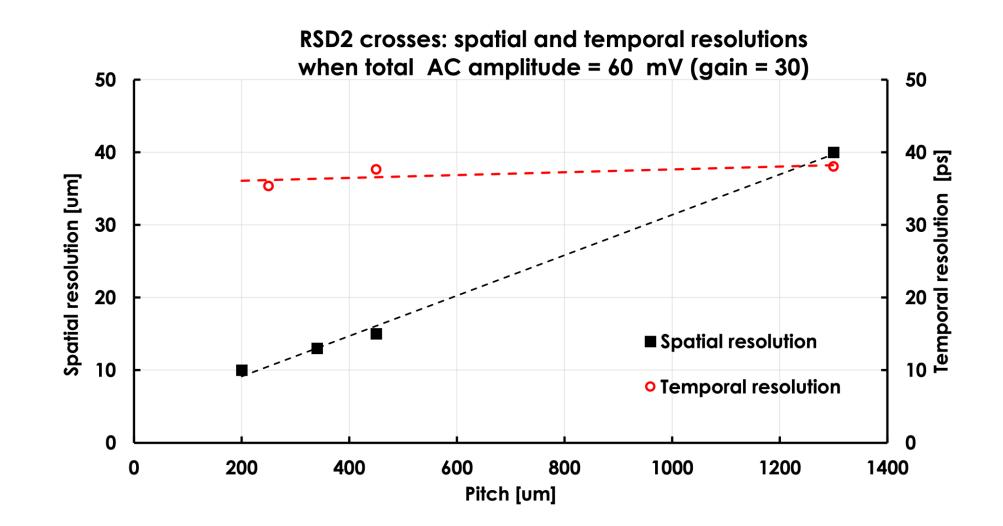
RSD temporal resolution (FBK RSD2 production)

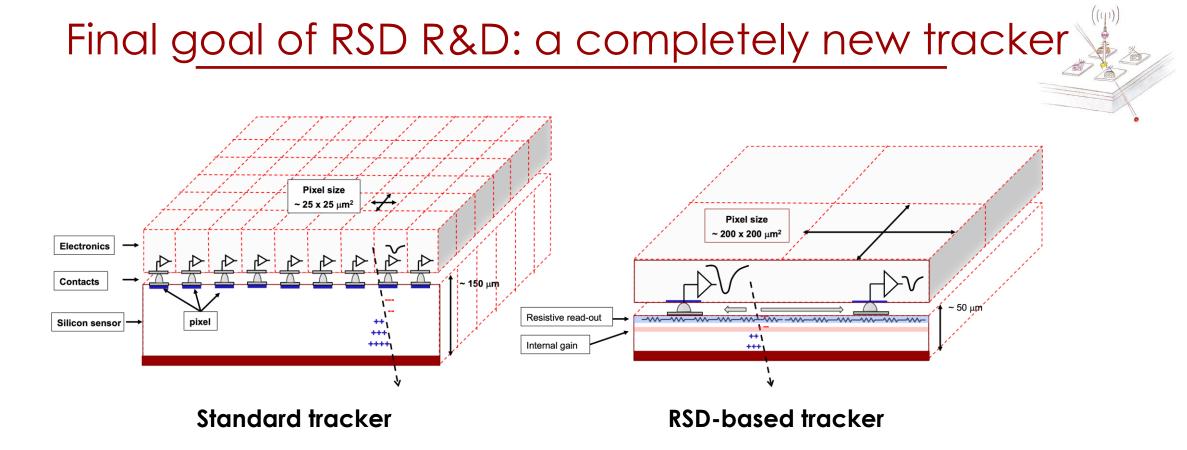
The resolution depends mostly upon the signal size and **weakly on the pixel size** RSDs at gain = 30 achieve a temporal jitter of about 20 ps



RSD2 Crosses: time jitter for 3 different pixel sizes

RSD2 performance summary





The design of a tracker based on RSD is truly innovative:

- It delivers ~ 20 30 ps temporal resolution
- For the same spatial resolution, the number of pixel is reduced by 50-100
- The electronic circuitry can be easily accomodated
- The power consumption is much lower, it might even be air cooled (~ 0.1-0.2 W/cm²)
- The sensors can be really thin

Z

Matching UFSD-RSD capabilities to the muColl requests

		cell size	sensor thickness	time resolution	spatial resolution	number of cells		High occupancy and levels. TI-LGAD can be used up to 1-2E15 n/cm ²		
VXD	в	25 μm × 25 μm pixels	50 µm	30 ps	$5\mu\text{m} imes 5\mu\text{m}$	729M				
	E	25 μm × 25 μm pixels	50 µm	30 ps	5 µm × 5 µm	462M		R&D in radiation harness needed to cover t full radiation field		
								Low occupancy and radiation levels. Ideal		
								for macro-pixels.		
п	в	$50 \mu m imes 1 mm$ macropixels	100 µm	60 ps	7 μm $ imes$ 90 μm	164M		Pixel size, spatial, and temporal resolutions		
	E	50 μ m $ imes$ 1 mm macropixels	100 µm	60 ps	7 μm $ imes$ 90 μm	127M		are a perfect fit for present RSD technology		
			1		·			RSD will strongly reduce the number of pixels		
							L			
								Very Low-occupancy and radiation levels.		
от	в	50 μm × 10 mm microstrips	100 µm	60 ps	7 μm $ imes$ 90 μm	117M		Long strips do not provide accurate temporal		
	E	$50 \ \mu m imes 10 \ mm microstrips$	100 µm	60 ps	7 μm $ imes$ 90 μm	56M		resolution.		
								Propose to replace it with RSD macro pads		

Conclusions

UFSD and RSD offer very good combined spatial and temporal performances These designs are a good fit to the need of the muColl design

		cell size	sensor thickness	time resolution	spatial resolution	number of cells	Cell size	Number of cells	Thickness	Detector
VXD	в	25 μm × 25 μm pixels	50 µm	30 ps	$5\mu m imes 5\mu m$	729M	To be decided		50 um	TI_LGAD
	Е	25 μm × 25 μm pixels	50 µm	30 ps	$5\mu\text{m} imes 5\mu\text{m}$	462M				
п	в	50 μ m $ imes$ 1 mm macropixels	100 µm	60 ps	7 $\mu m imes$ 90 μm	164M	200 um x 2 mm	1/8 # of present design	50 um	RSD
	E	50 μ m $ imes$ 1 mm macropixels	100 µm	60 ps	$7\mu\text{m} imes$ 90 μm	127M				
от	в	50 μm × 10 mm microstrips	100 µm	60 ps	7 μm × 90 μm	117M	200 um x 2 mm	Similar to the present design	50 um	RSD
	Е	$50 \ \mu m imes 10 \ mm$ microstrips	100 µm	60 ps	$7~\mu m imes$ 90 μm	56M				
				I						•

Proposed detector

Very difficult (impossible?) to achieve good timing with strips

Better to use macro-pads?

In Torino we are continuing the development of TI-LGAD and RSD for applications to the muColl tracker